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Efficient Generation of 509 nm Light by Sum-Frequency Mixing between two Tapered Diode Lasers

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Introduction

Many applications within the field of biomedicine, material processing and displays require light sources in the visible region. The green spectral region is not easily accessible by direct diode lasers, and therefore several methods exist for generation of green light. Many Watts of green light can be generated and with very good spectral and spatial quality by the process of second harmonic generation (SHG) [1]. Sum frequency generation (SFG) is another process of generating green light by mixing the output from two laser sources. SFG between two similar DBR tapered diode lasers was recently demonstrated to generate up to 3.9 W of nearly diffraction limited light at 531 nm [2]. In this work, we demonstrate the concept of combining two tapered diode lasers at different wavelengths (978 nm and 1063 nm), and thereby generate 509 nm green light by SFG.

The experimental setup

The SFG process is obtained by frequency adding of

• 6.17 W from a 978 nm tapered diode laser
• 8.06 W from a 1063 nm tapered diode laser
• Focused inside a periodically poled MgO doped lithium niobate crystal
• Using a 60 mm lens (proved to be optimum for the SFG process)

Concept for generation of laser light based on SFG between tapered diode lasers with different wavelengths:
• Efficient generation of diffraction limited light
• Desired wavelength with narrow linewidth
• Relatively high emission power

Summary

Such light sources could be introduced in different optical systems where either high power at a specific wavelength is needed, or in systems where the reduction of cost and footprint would be advantageous.

In this study we demonstrate:
• 1.7 W narrow linewidth green 509 nm light source
• Nearly diffraction limited light with M2=1.1 in the fast and the slow axis
• Optical to optical conversion efficiency of 12.1 %
• Non-linear conversion efficiency of 4.3 %/W

References


Results

In this study we demonstrate:

Figure 1: Setup for spectral beam combining of DBR-tapered diode lasers with subsequent sum-frequency generation.

Figure 2: An experimental result is compared to a numerical fit obtained by the SFG process.

Figure 3: A) M2 measurements (1/e)² of the SFG beam. The squares shows measurements of the slow axis, the circles shows the fast axis and the red curves represents the numerical fittings of the beam profiles. B) Focused beam profiles of the slow- and the fast axis for the SFG.

Figure 4: Ti:sapphire characteristics of A) CW emission and B) mode-locked emission, pumped by the 509 nm SFG laser.

Figure 5: A) Optical spectrum of the mode-locked Ti:sapphire laser, directly pumped by the 509 nm SFG laser. B) Image of the pumped Ti:Sapphire Laser.

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